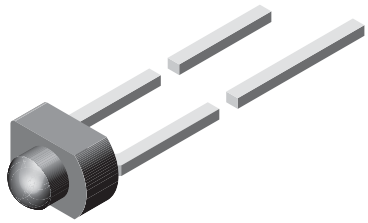
Universal LED, ∅ 1.8 mm Tinted Diffused Miniplast Package



FEATURES

- For DC and pulse operation
- Luminous intensity categorized
- End-to-end stackable in centre-to-centre spacing of 0.1" (2.54 mm)
- Lead (Pb)-free device

APPLICATIONS

- General indicating and lighting purposes

PRODUCT GROUP AND PACKAGE DATA

- Product group: LED
- Package: 1.8 mm (miniplast)
- Product series: standard
- Angle of half intensity: ± 20°

PARTS TABLE

PART	COLOR, LUMINOUS INTENSITY	TECHNOLOGY
TLUR2400	Red, I_V > 15 mcd (typ.)	GaAsP on GaP
TLUR2401	Red, I_V = (4 to 32) mcd	GaAsP on GaP

ABSOLUTE MAXIMUM RATINGS[1] TLUR240.

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V_R	6	V
DC Forward current		I_F	20	mA
Surge forward current	$t_p \leq 10$ µs	I_{FSM}	0.5	A
Power dissipation	$T_{amb} \leq 55$ °C	P_V	60	mW
Junction temperature		T_j	100	°C
Operating temperature range		T_{amb}	- 40 to + 100	°C
Storage temperature range		T_{stg}	- 55 to + 100	°C
Soldering temperature	t ≤ 3 s, 2 mm from body	T_{sd}	260	°C
	t ≤ 5 s, 4 mm from body	T_{sd}	260	°C
Thermal resistance junction/ ambient		R_{thJA}	450	K/W

Note:
[1] T_{amb} = 25 °C, unless otherwise specified

OPTICAL AND ELECTRICAL CHARACTERISTICS[1] TLUR240., RED							
PARAMETER	**TEST CONDITION**	**PART**	**SYMBOL**	**MIN**	**TYP.**	**MAX**	**UNIT**
Luminous intensity [2]	I_F = 10 mA	TLUR2400	I_V	4	15		mcd
		TLUR2401	I_V	4		32	mcd
Dominant wavelength	I_F = 10 mA		λ_d		630		nm
Peak wavelength	I_F = 10 mA		λ_p		640		nm
Angle of half intensity	I_F = 10 mA		φ		± 20		deg
Forward voltage	I_F = 20 mA		V_F		2	3	V
Reverse voltage	I_R = 10 µA		V_R	6	15		V
Junction capacitance	V_R = 0, f = 1 MHz		C_j		50		pF

Note:
[1] T_{amb} = 25 °C, unless otherwise specified
[2] In one packing unit $I_{Vmin}/I_{Vmax} \leq 0.5$

TYPICAL CHARACTERISTICS

T_{amb} = 25 °C, unless otherwise specified

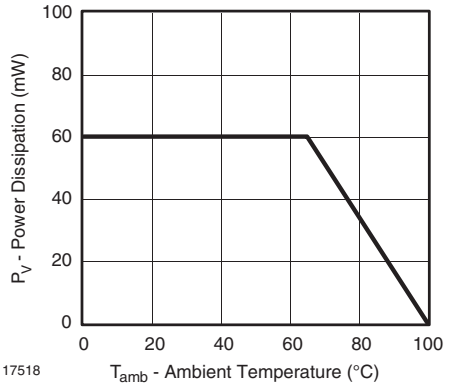


Figure 1. Power Dissipation vs. Ambient Temperature

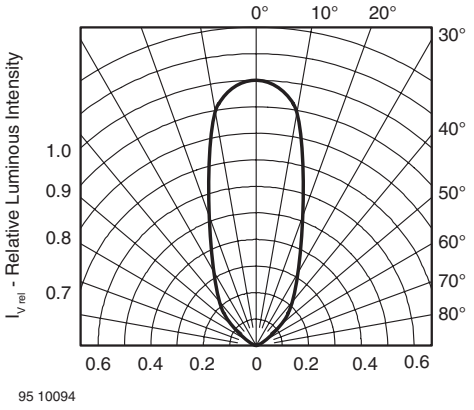


Figure 3. Rel. Luminous Intensity vs. Angular Displacement

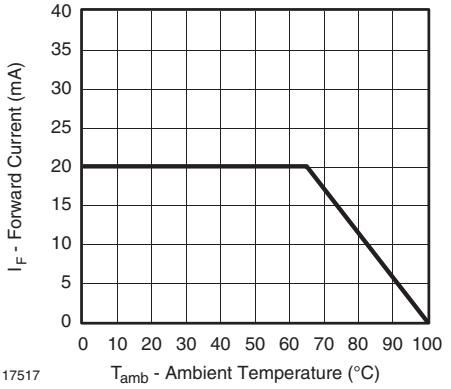


Figure 2. Forward Current vs. Ambient Temperature

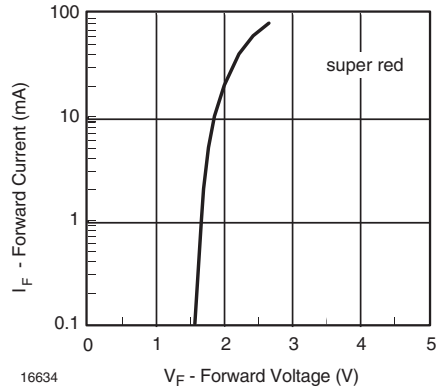


Figure 4. Forward Current vs. Forward Voltage

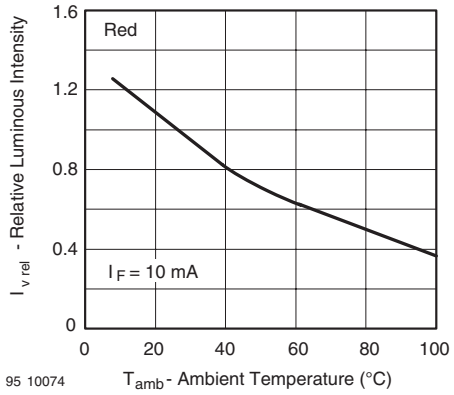


Figure 5. Rel. Luminous Intensity vs. Ambient Temperature

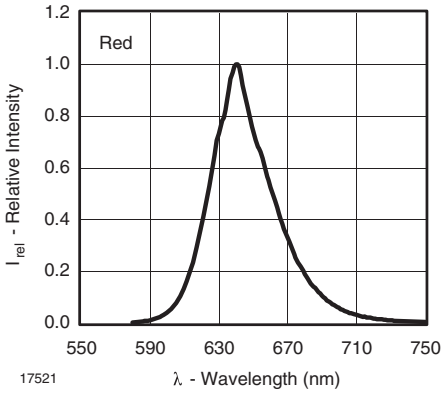


Figure 7. Relative Intensity vs. Wavelength

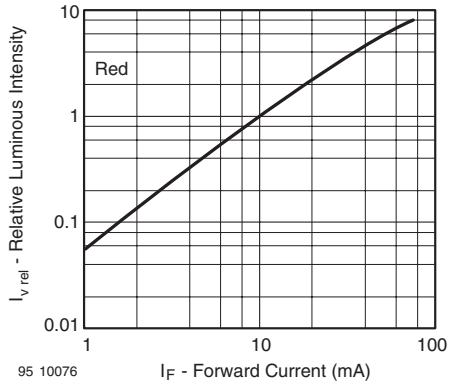
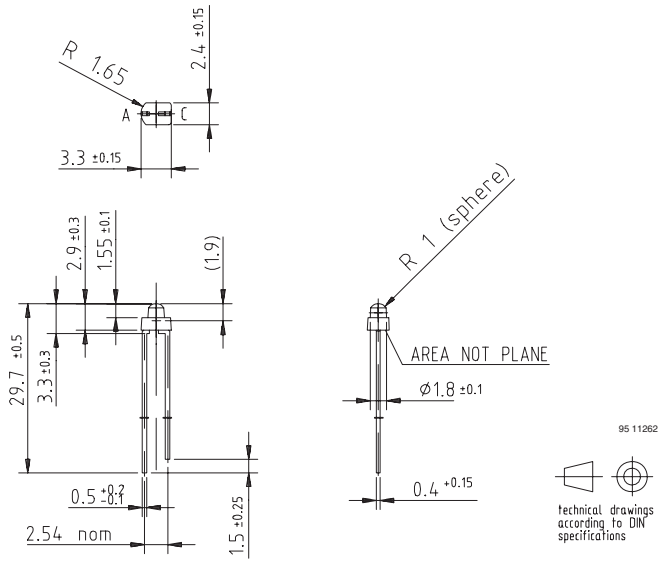


Figure 6. Relative Luminous Intensity vs. Forward Current

PACKAGE DIMENSIONS in millimeters



Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design
and may do so without further notice.
Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany

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